Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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BIPOLAR ANALOG INTEGRATED CIRCUIT μ PC29L00 Series

THREE TERMINAL LOW DROPOUT VOLTAGE REGULATOR

DESCRIPTION

 μ PC29L00 Series are low dropout regulators which have 100 mA capable for the output current. The variation of output voltage is 3 V, 3.3 V, 4 V and 5 V.

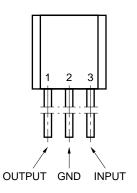
FEATURES

- Low dropout voltage. VDIF ≤ 0.3 V
- · Built-in overcurrent protection circuit.
- · Built-in thermal shut-down circuit.

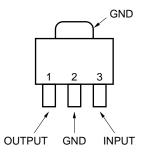
ORDERING INFORMATION

Output Voltage	Type Number	Package
3 V	μPC29L03J	TO-92
	μPC29L03T	SOT-89
3.3 V	μPC29L33J	TO-92
	μPC29L33T	SOT-89
4 V	μPC29L04J	TO-92
	μPC29L04T	SOT-89
5 V	μPC29L05J	TO-92
	μPC29L05T	SOT-89

CONNECTION DIAGRAM (TOP VIEW) μPC29L00J Series

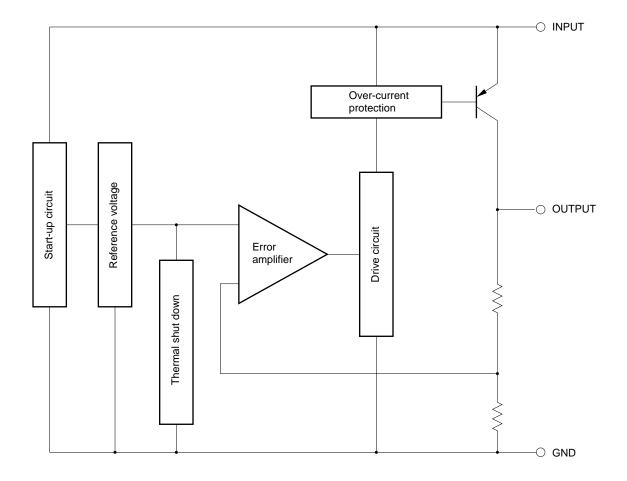


 μ PC29L00T Series





BLOCK DIAGRAM





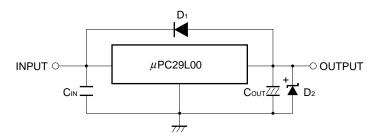
ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, Unless otherwise specified.)

PARAMETER	SYMBOL		RATING	UNIT
Input Voltage	Vin		16	V
Internal Power Dissipation	Рт	J	700 Note 1	mW
		Т	400 Note 1	
			2000 Note 1, 2	
Operating Ambient Temperature Range	TA		-30 to +85	°C
Operating Junction Temperature Range	TJ		-30 to +150	°C
Storage Temperature Range	T _{stg}	-55 to +150		°C
Thermal Resistance (Junction to Case)	Rth(J - C)	J –		°C/W
		Т	30	
Thermal Resistance (Junction to Ambient)	Rth(J - A)	J 180		°C/W
		Т	315	
			62.5 Note 2	

Notes 1. $T_A \le 25 \,^{\circ}C$

2. With the 16 $cm^2 \times 0.7$ mm ceramic substrate

TYPICAL CONNECTION



C_{IN} : 0.1 to 0.47 μ F. C_{OUT} : More than 10 μ F. D₁ : Need for Vo > V_{IN}. D₂ : Need for Vo < GND.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	TYPE NUMBER	MIN.	TYP.	MAX.	UNIT
Input Voltage	VIN	μPC29L03	3.5		9	V
		μPC29L33	3.8		9	
		μPC29L04	4.5		12	
		μPC29L05	5.5		12	
Output Current	lo	All	0		40	mA
Operating Ambient Temperature Range	TA	All	-30		+85	°C
Operating Junction Temperature Range	TJ	All	-30		+125	°C



 μ PC29L03 (V_{IN} = 4 V, Io = 40 mA, T_J = 25 °C, Unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Voltage	Vo		2.88	3.0	3.12	V
		$3.5 \text{ V} \leq \text{V}_{\text{IN}} \leq 9 \text{ V}, 1 \text{ mA} \leq \text{Io} \leq 40 \text{ mA}, \\ 0 \text{ °C} \leq \text{T}_{\text{J}} \leq 125 \text{ °C}$	2.85		3.15	
		$ 4.5 \text{ V} \leq \text{V}_{\text{IN}} \leq 5.5 \text{ V}, \text{ 1 mA} \leq \text{Io} \leq \text{100 mA}, \\ 0 \text{ °C} \leq \text{T}_{\text{J}} \leq \text{125 °C} $	2.85		3.15	
Line Regulation	REGIN	3.5 V ≤ V _{IN} ≤ 12 V		4	50	mV
		3.5 V ≤ V _{IN} ≤ 9 V		2	20	
Load Regulation	REG∟	1 mA ≤ lo ≤ 100 mA		37	50	mV
		1 mA ≤ lo ≤ 40 mA		15	20	
Quiescent Current	IBIAS	lo = 0		1.5	2.0	mA
		lo = 100 mA		10	20	mA
Start-up Current	IBIAS(S)	Io = 0 mA, before Vo regulation		6	20	mA
Quiescent Current Change	ΔI BIAS	4 V ≤ V _{IN} ≤ 12 V, 0 °C ≤ T _J ≤ 125 °C			1.0	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		25		μV_{rms}
Ripple Rejection	R∙R	f = 120 Hz, 4 V ≤ V _{IN} ≤ 9 V	48	66		dB
Dropout Voltage	VDIF	Io = 40 mA, 0 °C ≤ T _J ≤ 125 °C		0.15	0.3	V
Peak Output Current	lOpeak	V _{IN} = 5 V		190		mA
Short Circuit Current	Oshort	V _{IN} = 12 V		100		mA
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	Io = 5 mA, 0 °C ≤ T _J ≤ 125 °C		-0.5		mV/°C



 μ PC29L33 (V_{IN} = 5 V, Io = 40 mA, T_J = 25 °C, Unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Voltage	Vo		3.17	3.3	3.43	V
		$3.8 \text{ V} \leq \text{V}_{\text{IN}} \leq 10 \text{ V}, \text{ 1 mA} \leq \text{Io} \leq 40 \text{ mA}, \\ 0 \text{ °C} \leq \text{T}_{\text{J}} \leq 125 \text{ °C}$	3.14		3.46	
		$ 4.5 \text{ V} \leq \text{V}_{\text{IN}} \leq 5.5 \text{ V}, \ 1 \text{ mA} \leq \text{Io} \leq 100 \text{ mA}, \\ 0 \text{ °C} \leq \text{T}_{\text{J}} \leq 125 \text{ °C} $	3.14		3.46	
Line Regulation	REGIN	3.8 V ≤ V _{IN} ≤ 12 V		4	50	mV
		3.8 V ≤ V _{IN} ≤ 9 V		2	20	
Load Regulation	REGL	1 mA ≤ lo ≤ 100 mA		37	50	mV
		1 mA ≤ lo ≤ 40 mA		16	20	
Quiescent Current	Івіаѕ	lo = 0		1.5	2.0	mA
		lo = 100 mA		10	20	mA
Start-up Current	IBIAS(S)	Io = 0 mA, before Vo regulation		19	30	mA
Quiescent Current Change	ΔI BIAS	4.3 V ≤ V _{IN} ≤ 12 V, 0 °C ≤ T _J ≤ 125 °C			1.0	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		28		μV_{rms}
Ripple Rejection	R∙R	f = 120 Hz, 4.3 V ≤ V _{IN} ≤ 9 V	48	65		dB
Dropout Voltage	VDIF	Io = 40 mA, 0 °C ≤ T _J ≤ 125 °C		0.15	0.3	V
Peak Output Current	lOpeak	V _{IN} = 5 V		190		mA
Short Circuit Current	Oshort	V _{IN} = 12 V		100		mA
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	Io = 5 mA, 0 °C ≤ T _J ≤ 125 °C		-0.6		mV/°C



 μ PC29L04 (V_{IN} = 6 V, Io = 40 mA, T_J = 25 °C, Unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Voltage	Vo		3.84	4.0	4.16	V
		$ 4.5 \text{ V} \leq \text{V}_{\text{IN}} \leq 12 \text{ V}, \text{ 1 mA} \leq \text{Io} \leq 40 \text{ mA}, \\ 0 \text{ °C} \leq \text{T}_{\text{J}} \leq 125 \text{ °C} $	3.80		4.20	
		$V_{IN} = 6 \text{ V}, 1 \text{ mA} \le I_0 \le 100 \text{ mA},$ $0 \text{ °C} \le T_J \le 125 \text{ °C}$	3.80		4.20	
Line Regulation	REGIN	4.5 V ≤ V _{IN} ≤ 12 V		4	30	mV
Load Regulation	REG∟	1 mA ≤ lo ≤ 100 mA		33	60	mV
		1 mA ≤ lo ≤ 40 mA		14	30	
Quiescent Current	IBIAS	lo = 0		1.6	2.0	mA
		lo = 100 mA		10	20	mA
Start-up Current	IBIAS(S)	Io = 0 mA, before Vo regulation		20	50	mA
Quiescent Current Change	ΔI BIAS	4.5 V ≤ V _{IN} ≤ 12 V, 0 °C ≤ T _J ≤ 125 °C			1.0	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		35		μV_{rms}
Ripple Rejection	R∙R	f = 120 Hz, 5 V ≤ V _{IN} ≤ 10 V	47	65		dB
Dropout Voltage	VDIF	Io = 40 mA, 0 °C ≤ TJ ≤ 125 °C		0.15	0.3	V
Peak Output Current	lOpeak	V _{IN} = 6 V		220		mA
Short Circuit Current	Oshort	V _{IN} = 12 V		100		mA
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	$I_{O} = 5$ mA, 0 °C \leq $T_{J} \leq$ 125 °C		0.2		mV/°C

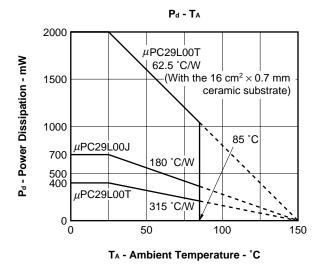


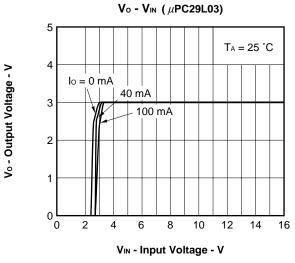
 μ PC29L05 (V_{IN} = 6 V, Io = 40 mA, T_J = 25 °C, Unless otherwise specified)

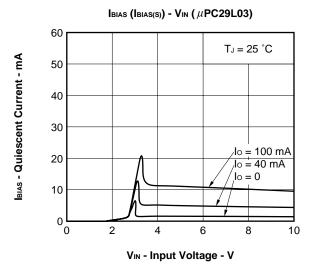
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Voltage	Vo		4.8	5.0	5.2	V
			4.75		5.25	
		$V_{IN} = 6 \text{ V}, 1 \text{ mA} \le I_0 \le 100 \text{ mA},$ $0 \text{ °C} \le T_J \le 125 \text{ °C}$	4.75		5.25	
Line Regulation	REGIN	5.5 V ≤ V _{IN} ≤ 12 V		4	30	mV
Load Regulation	REGL	1 mA ≤ lo ≤ 100 mA		35	80	mV
		1 mA ≤ lo ≤ 40 mA		15	30	
Quiescent Current	IBIAS	lo = 0		1.6	2.0	mA
		lo = 100 mA		10	20	mA
Start-up Current	IBIAS(S)	lo = 0 mA, before Vo regulation		50	90	mA
Quiescent Current Change	ΔI BIAS	$6~V \le V_{IN} \le 12~V,~0~^{\circ}C \le T_{J} \le 125~^{\circ}C$			1.0	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		40		μV_{rms}
Ripple Rejection	R∙R	f = 120 Hz, 6 V ≤ V _{IN} ≤ 11 V	46	62		dB
Dropout Voltage	VDIF	Io = 40 mA, 0 °C ≤ T _J ≤ 125 °C		0.15	0.3	V
Peak Output Current	lOpeak	V _{IN} = 7 V		210		mA
Short Circuit Current	Oshort	V _{IN} = 12 V		100		mA
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	$Io = 5$ mA, 0 °C \leq T $_{\rm J} \leq$ 125 °C		0.2		mV/°C

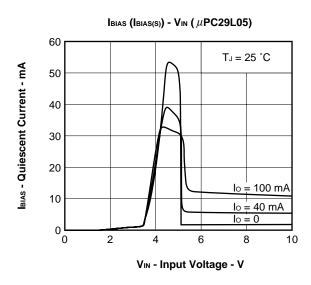


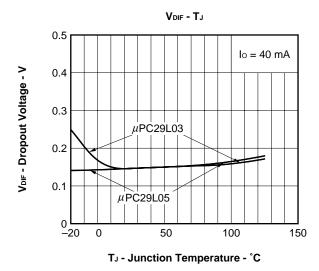
TYPICAL CHARACTERISTICS

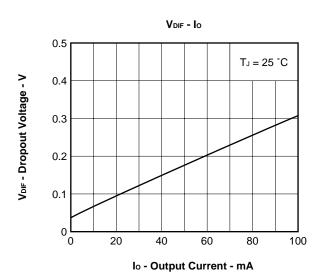




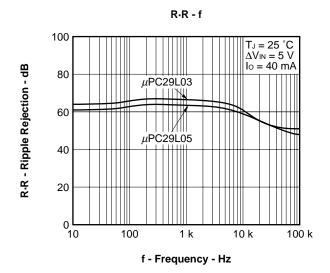


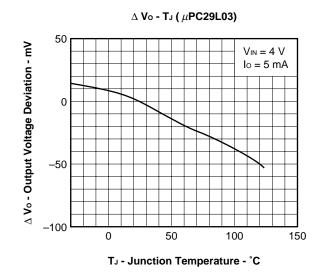


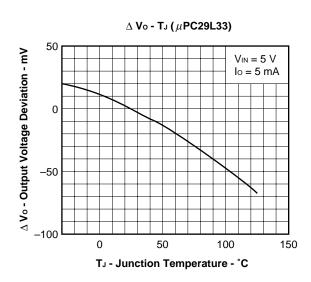


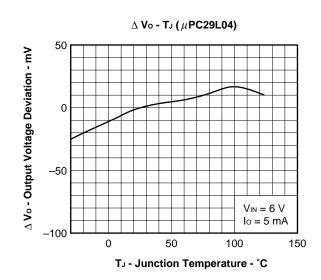


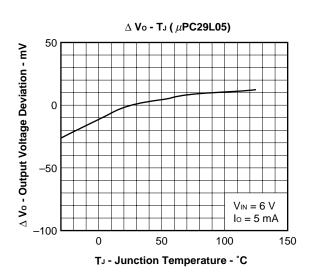
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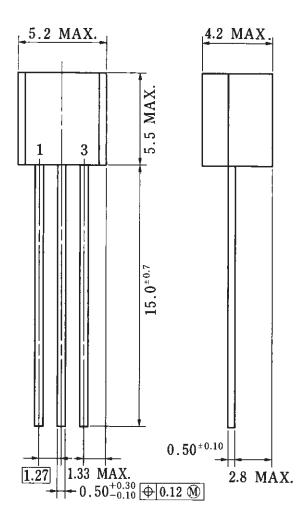




PACKAGE DIMENSIONS (Unit: mm)

 μ PC29L00J Series

3PIN PLASTIC SIP (TO-92)

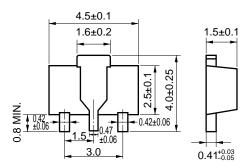


P3J-127B



 μ PC29L00T Series

SOT-89





RECOMMENDED SOLDERING CONDITIONS

The following conditions (see table below) must be met when soldering this product.

Please consult with our sales offices in case other soldering process is used, or in case soldering is done under different conditions.

TYPES OF THROUGH HOLE MOUNT DEVICE

 μ PC29L00J Series

Soldering Process	Soldering Conditions	Symbol
Wave soldering	Solder temperature: 260 °C or below. Flow Time: 10 seconds or below.	

TYPES OF SURFACE MOUNT DEVICE

For more details, refer to our document "Semiconductor Device Mounting Manual" (IEI-1207).

μ PC29L00T Series

Soldering Process	Soldering Conditions	Symbol
Infrared ray reflow	Peak package's temperature: 235 °C or below. Reflow time: 30 seconds or below (210 °C or higher). Number of flow process: 2. Exposure limit Note: None.	IR35-00-2
Vapor phase soldering	Peak package's temperature: 215 °C or below. Reflow time: 40 seconds or below (200 °C or higher). Number of flow process: 2. Exposure limit Note: None.	VP15-00-2
Wave soldering	Solder temperature: 260 °C or below. Flow time: 10 seconds or below. Number of flow process: 1. Exposure limit Note: None.	WS60-00-1

Note Exposure limit before soldering after dry-pack package is opened.

Remark Storage conditions: 25 °C and relative humidity at 65 % or less.

Caution Do not apply more than a single process at once, except for "Partial heating method".

REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	IEI-1212
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134

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Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

The quality grade of NEC devices in "Standard" unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact NEC Sales Representative in advance.

Anti-radioactive design is not implemented in this product.